

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	33586	metal adj oxide adj semiconductor	USPAT	2007/02/19 16:42
2	BRS	L2	1374	L1 and (sic "silicon carbide")	US- PGPUB; USPAT; EPO; DERWE NT	2007/02/19 16:43
3	BRS	L3	5	2 and (miscut "cleave angle" "cleave face" "cleave facet" "cut direction" "miscut direction")	US- PGPUB; USPAT; EPO; DERWE NT	2007/02/19 16:44
4	BRS	L4	5	3 and @ad<"20041124"	US- PGPUB; USPAT; EPO; DERWE NT	2007/02/19 16:45